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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## 2SK2684(L), 2SK2684(S)

# Silicon N Channel MOS FET High Speed Power Switching

REJ03G1022-0200

(Previous: ADE-208-542)

Rev.2.00

Sep 07, 2005

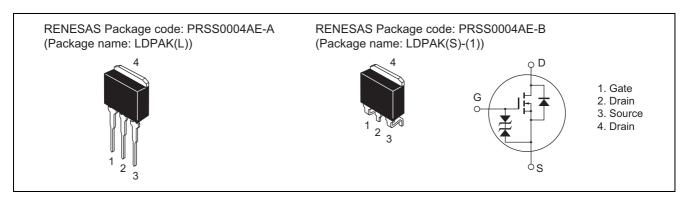
## **Application**

High speed power switching

#### **Features**

- Low on-resistance
- High speed switching
- · Low drive current
- No secondary breakdown
- Suitable for switching regulator, DC-DC converter

#### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

| Item                                      | Symbol                   | Ratings     | Unit |
|---|--------------------------|-------------|------|
| Drain to source voltage                   | V <sub>DSS</sub>         | 30          | V    |
| Gate to source voltage                    | V <sub>GSS</sub>         | ±20         | V    |
| Drain current                             | I <sub>D</sub>           | 30          | А    |
| Drain peak current                        | I <sub>D(pulse)</sub> *1 | 120         | А    |
| Body to drain diode reverse drain current | I <sub>DR</sub>          | 30          | А    |
| Channel dissipation                       | Pch*2                    | 50          | W    |
| Channel temperature                       | Tch                      | 150         | °C   |
| Storage temperature                       | Tstg                     | -55 to +150 | °C   |

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1 %

2. Value at Tc = 25°C

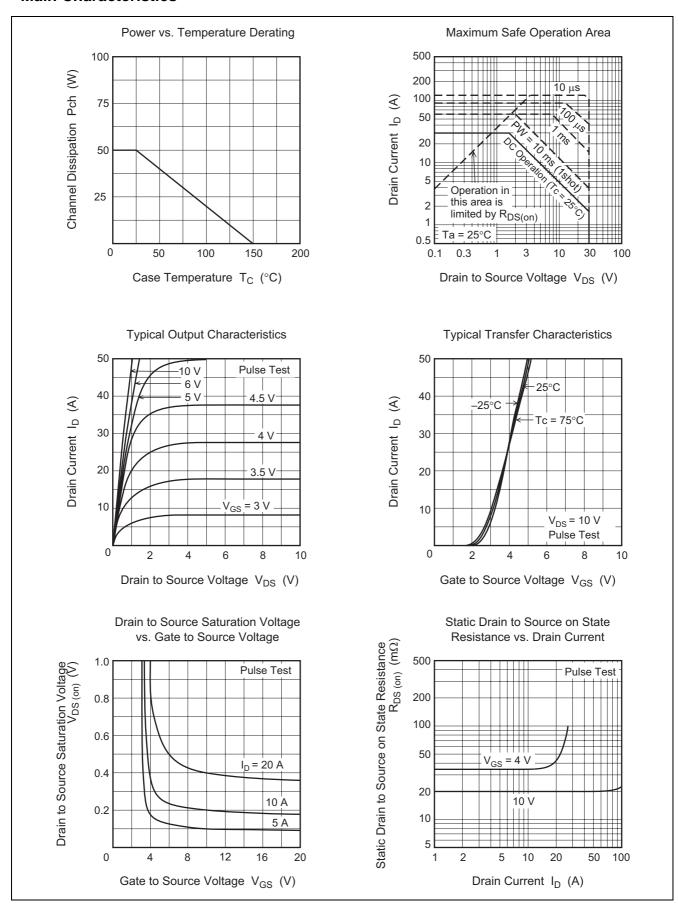
## **Electrical Characteristics**

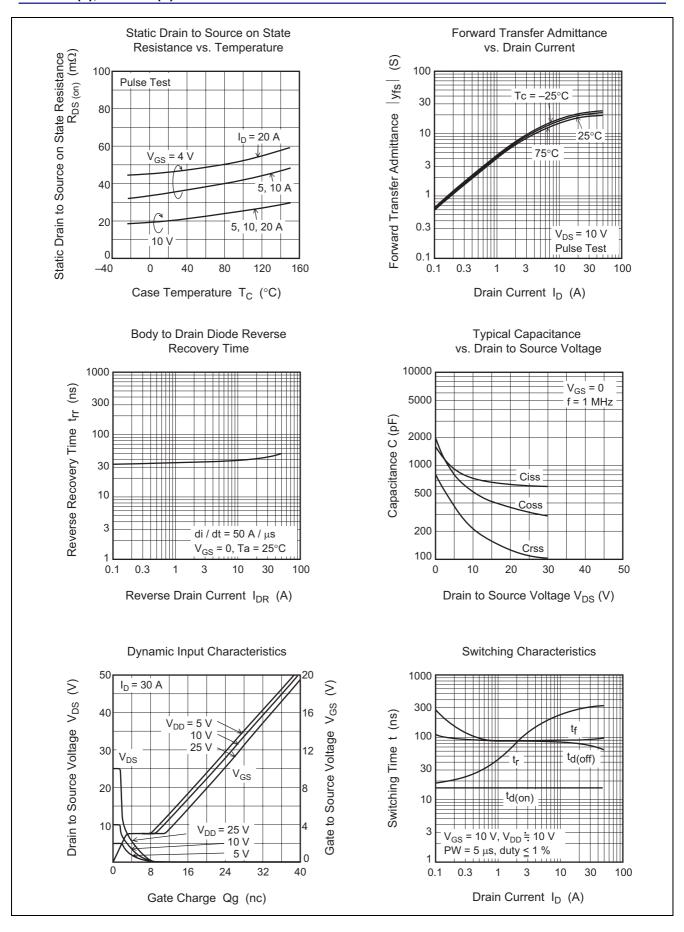
 $(Ta = 25^{\circ}C)$ 

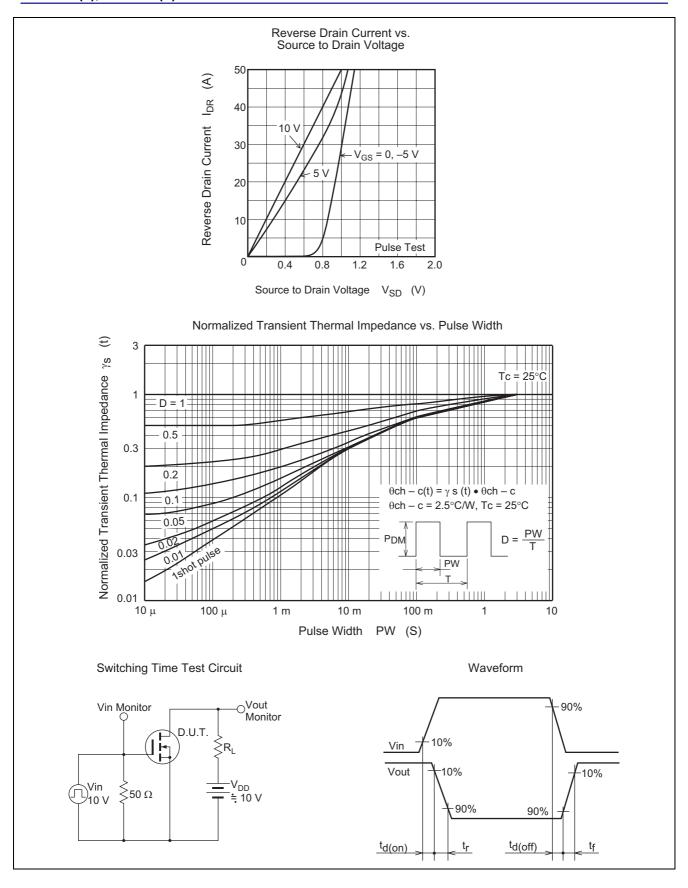
| Item                                 | Symbol              | Min | Тур | Max | Unit | Test Conditions                                  |
|--------------------------------------|---------------------|-----|-----|-----|------|--|
| Drain to source breakdown voltage    | $V_{(BR)DSS}$       | 30  | _   | _   | V    | $I_D = 10 \text{ mA}, V_{GS} = 0$                |
| Gate to source breakdown voltage     | $V_{(BR)GSS}$       | ±20 | _   | _   | V    | $I_G = \pm 100 \ \mu A, \ V_{DS} = 0$            |
| Zero gate voltage drain current      | I <sub>DSS</sub>    | _   | _   | 10  | μΑ   | $V_{DS} = 30 \text{ V}, V_{GS} = 0$              |
| Gate to source leak current          | $I_{GSS}$           | _   | _   | ±10 | μΑ   | $V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$          |
| Gate to source cutoff voltage        | $V_{GS(off)}$       | 1.0 | _   | 2.0 | V    | $I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$      |
| Static drain to source on state      | R <sub>DS(on)</sub> | _   | 20  | 28  | mΩ   | $I_D = 15 \text{ A}, V_{GS} = 10 \text{ V}^{*3}$ |
| resistance                           | R <sub>DS(on)</sub> | _   | 35  | 50  | mΩ   | $I_D = 15 \text{ A}, V_{GS} = 4 \text{ V}^{*3}$  |
| Forward transfer admittance          | y <sub>fs</sub>     | 12  | 18  | _   | S    | $I_D = 15 \text{ A}, V_{DS} = 10 \text{ V}^{*3}$ |
| Input capacitance                    | Ciss                | _   | 750 | _   | pF   | $V_{DS} = 10 \text{ V}, V_{GS} = 0,$             |
| Output capacitance                   | Coss                | _   | 520 | _   | pF   | f = 1 MHz  |
| Reverse transfer capacitance         | Crss                | _   | 210 | _   | pF   | ]  |
| Turn-on delay time                   | t <sub>d(on)</sub>  | _   | 16  | _   | ns   | $V_{GS} = 10 \text{ V}, I_D = 15 \text{ A},$     |
| Rise time                            | t <sub>r</sub>      | _   | 260 | _   | ns   | $R_L = 0.67 \Omega$                              |
| Turn-off delay time                  | t <sub>d(off)</sub> | _   | 85  | _   | ns   | ]  |
| Fall time                            | t <sub>f</sub>      | _   | 90  | _   | ns   | ]  |
| Body to drain diode forward voltage  | $V_{DF}$            | _   | 1.0 | _   | V    | $I_F = 30 \text{ A}, V_{GS} = 0$                 |
| Body to drain diode reverse recovery | t <sub>rr</sub>     | _   | 45  | _   | ns   | I <sub>F</sub> = 30 A, V <sub>GS</sub> = 0       |
| time                                 |                     |     |     |     |      | $di_F/dt = 50 A/\mu s$                           |

Note: 3. Pulse test

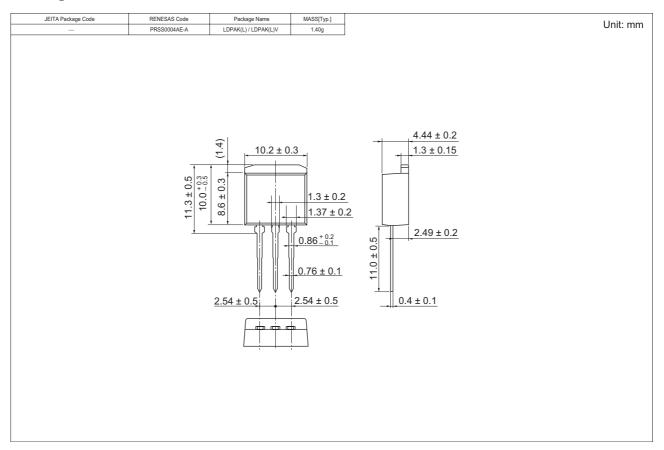
### **Main Characteristics**

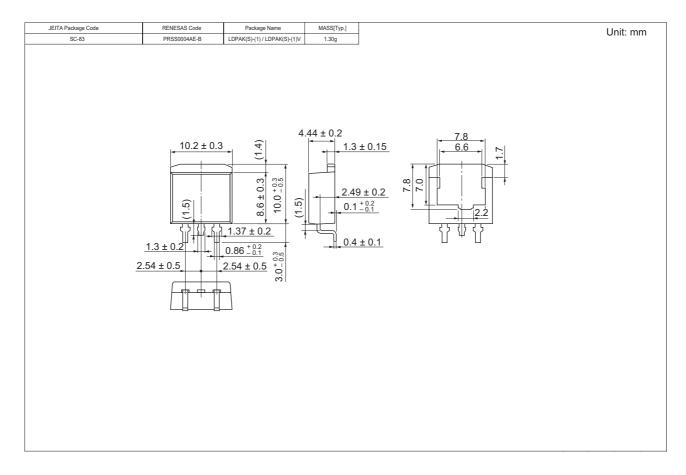






## **Package Dimensions**





## **Ordering Information**

| Part Name    | Quantity | Shipping Container |
|--------------|----------|--------------------|
| 2SK2684L-E   | 500 pcs  | Box (Sack)         |
| 2SK2684STL-E | 1000 pcs | Taping             |

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